Virtual Memory III

CSE 351 Autumn 2023

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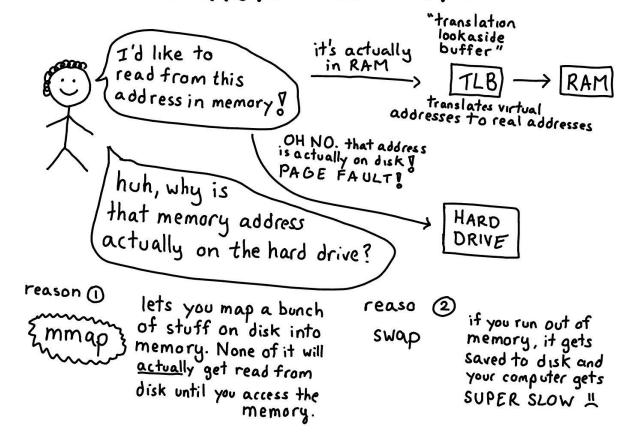
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E VIRTUAL MEMORY =

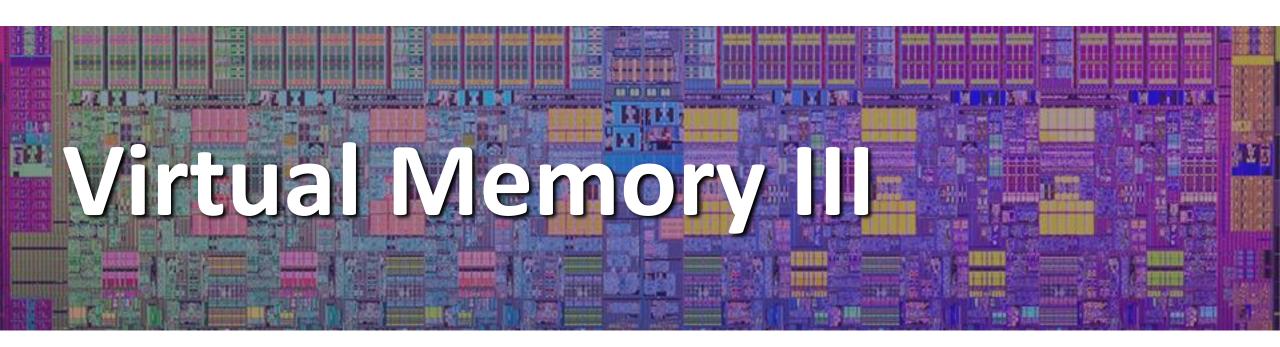


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Relevant Course Information

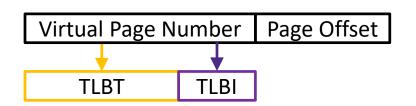
- HW24 due tonight; HW25 due Wednesday (12/6)
- Lab 5 due Thursday (12/7)
 - Recommended that you watch all of the Lab 5 helper videos
- ❖ No lessons in Week 11 "normal" lectures
- ❖ Final Exam: 12/11-13
 - Similar to midterm; Gilligan's Island Rule in effect
 - Final review section on 12/7
 - Review Session: Fri, 12/8, evening
 - More info to be released on Ed Discussion

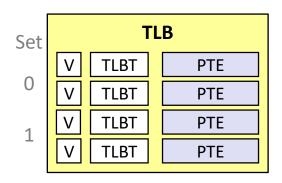
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Lesson Summary

- Introduced the translation lookaside buffer (TLB) as a cache for page table entries (PTEs)
 - Try to avoid accessing the page table in memory
 - Split VPN into TLB Tag and TLB Index based on # of sets in TLB
 - Management bits include valid (like \$, not PT) and TLB tag

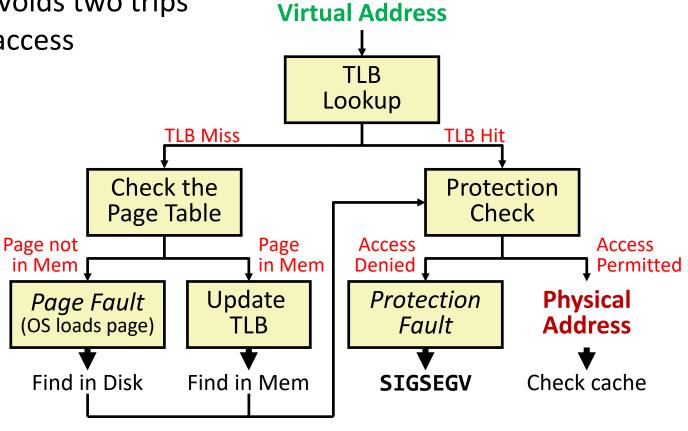




Address Translation

- VM is complicated, but also elegant and effective
 - Level of indirection to provide isolated memory & caching

 TLB as a cache of page tables avoids two trips to memory for every memory access

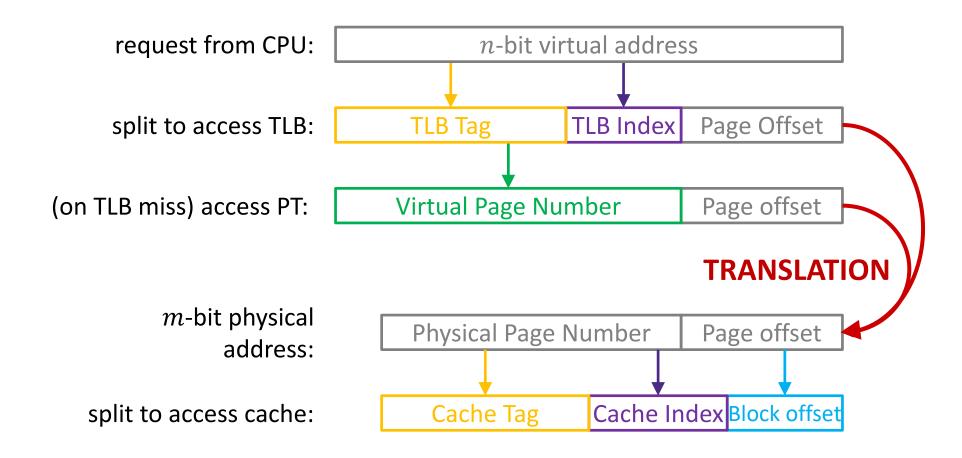


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Fetching Data on a Memory Read

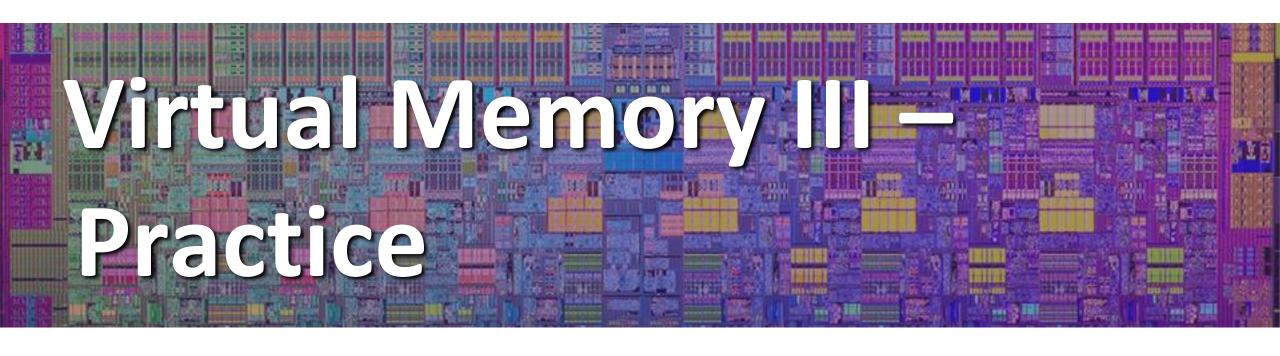
- 1) Address Translation (check TLB)
 - Input: VPN, Output: PPN
 - TLB Hit: Fetch translation, return PPN
 - TLB Miss: Check page table (in memory)
 - Page Table Hit: Load page table entry into TLB
 - Page Fault: Fetch page from disk to memory, update corresponding page table entry, then load entry into TLB
- 2) Fetch Data (check cache)
 - Input: physical address, Output: data
 - Cache Hit: Return data value to processor
 - Cache Miss: Fetch data value from memory, store it in cache, return it to processor

Address Manipulation



Lesson Q&A

- Terminology:
 - Translation Lookaside Buffer (TLB): TLB Hit, TLB Miss
- Learning Objectives:
 - Determine virtual memory parameters related to addresses, page tables, and TLBs.
 - Perform address translations (virtual address → physical address).
 - Describe the relationships between virtual memory parameters and policies.
- What lingering questions do you have from the lesson?



Concept Questions

What do Page Tables map?

Where are Page Tables located?

How many Page Tables are there?

```
one per process
```

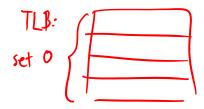
* True / False: Virtual Addresses that are contiguous will always be contiguous in

* TLB stands for <u>translation lookaside buffer</u> and stores <u>page table entries</u>

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VM Parameters Questions

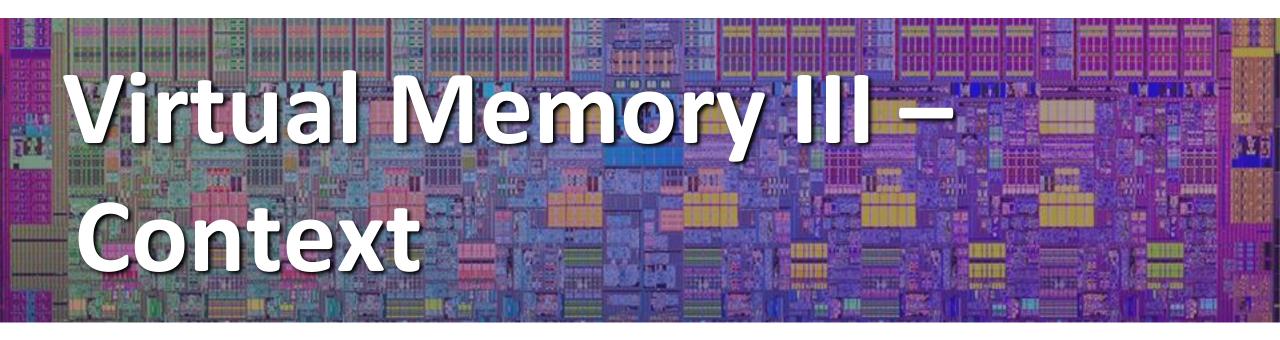
- Our system has the following properties
 - 1 MiB of physical address space m = 20 bits
 - 4 GiB of virtual address space n = 32 bits
 - 32 KiB page size p = 15 6t/s
 - 4-entry fully associative TLB with LRU replacement



a) Fill in the following blanks:

Entries in a page table
$$20$$
 Minimum bit-width of PTBR \leftarrow physical address of PT $2^{n-p} \leftarrow \#$ of virtual pages

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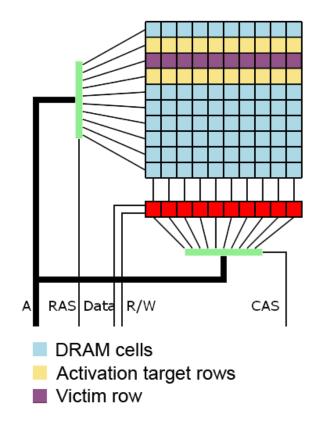


DRAMMER Security Attack

- Relevance: Uses your system's memory setup to gain elevated privileges
 - Ties together some of what we've learned about virtual memory and processes
- Interest: It's a software attack that uses only hardware vulnerabilities and requires no user permissions
- Recent: DRAMMER announced in October 2016; latest attack variant (Half Double) announced May 2021
 - Other recent variants of underlying vulnerability (row hammer) as recent as 2018

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- Dynamic RAM (DRAM) has gotten denser over time
 - DRAM cells physically closer and use smaller charges
 - More susceptible to "disturbance errors" (interference)
- DRAM capacitors need to be "refreshed" periodically (~64 ms)
 - Lose data when loss of power
 - Capacitors accessed in rows
- Rapid accesses to one row can flip bits in an adjacent row!
 - ~ 100K to 1M times



By Dsimic (modified), CC BY-SA 4.0, https://commons.wikimedia.org/w/ /index.php?curid=38868341

Row Hammer Exploit

- Force constant memory access
 - Read then flush the cache
 - clflush flush cache line
 - Invalidates cache line containing the specified address
 - Not available in all machines or environments
 - Want addresses X and Y to fall in activation target row(s)
 - Good to understand how banks of DRAM cells are laid out
- The row hammer effect was discovered in 2014
 - Only works on certain types of DRAM (2010 onwards)
 - These techniques target x86 machines

```
hammertime:
mov (X), %eax
mov (Y), %ebx
clflush (X)
clflush (Y)
jmp hammertime
```

Consequences of Row Hammer

- Row hammering process can affect another process via memory
 - Circumvents virtual memory protection scheme
 - Memory needs to be in an adjacent row of DRAM
- Worse: privilege escalation
 - Page tables live in memory!
 - Hope to change PPN to access other parts of memory, or change permission bits

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 Goal: gain read/write access to a page containing a page table, hence granting process read/write access to all of physical memory

Effectiveness?

- Doesn't seem so bad random bit flip in a row of physical memory
 - Vulnerability affected by system setup and physical condition of memory cells

Improvements:

- Double-sided row hammering increases speed & chance
- Do system identification first (e.g., Lab 4)
 - Use timing to infer memory row layout & find "bad" rows
 - Allocate a huge chunk of memory and try many addresses, looking for a reliable/repeatable bit flip
- Fill up memory with page tables first
 - fork extra processes; hope to elevate privileges in any page table

What's DRAMMER?

- No one previously made a huge fuss
 - Prevention: error-correcting codes, target row refresh, higher DRAM refresh rates
 - Often relied on special memory management features
 - Often crashed system instead of gaining control
- Research group found a deterministic way to induce row hammer exploit in a non-x86 system (ARM)
 - Relies on predictable reuse patterns of standard physical memory allocators
 - Universiteit Amsterdam, Graz University of Technology, and University of California, Santa Barbara

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DRAMMER Demo Video

- https://youtu.be/x6hL-obNhAw
 - It's a shell, so not that sexy-looking, but still interesting
 - Apologies that the text is so small on the video



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How did we get here?

- Computing industry demands more and faster storage with lower power consumption
- Ability of user to circumvent the caching system
 - clflush is an unprivileged instruction in x86
 - Other commands exist that skip the cache
- Availability of virtual to physical address mapping
 - Example: /proc/self/pagemap on Linux (not human-readable)

- Google patch for Android (Nov. 8, 2016)
 - Patched the ION memory allocator

More reading for those interested

- DRAMMER paper: https://vvdveen.com/publications/drammer.pdf
- Google Project Zero: https://googleprojectzero.blogspot.com/2015/03/exploiting-dram-rowhammer-bug-to-gain.html
- First rowhammer paper: https://users.ece.cmu.edu/~yoonguk/papers/kim-isca14.pdf
- Latest non-uniform, frequency-based exploit: https://comsec.ethz.ch/research/dram/blacksmith/
- Wikipedia: https://en.wikipedia.org/wiki/Row hammer

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Discussion Question

- Discuss the following question(s) in groups of 3-4 students
 - I will call on a few groups afterwards so please be prepared to share out
 - Be respectful of others' opinions and experiences
- We tend to think of software as existing in a realm abstracted away from hardware; however, this class has been about the interactions between hardware and software
 - Based on what we've learned in this class, what are some ways that your choice of hardware setup may affect your "day-to-day" as a software engineer?

Group Work Time

- During this time, you are encouraged to work on the following:
 - 1) If desired, continue your discussion
 - 2) Work on the homework problems
 - 3) Work on the current lab

Resources:

- You can revisit the lesson material
- Work together in groups and help each other out
- Course staff will circle around to provide support